

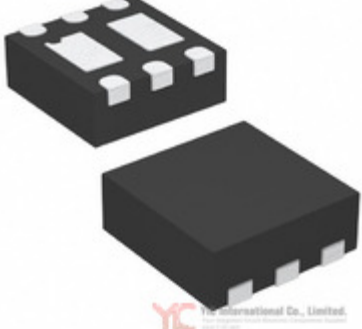




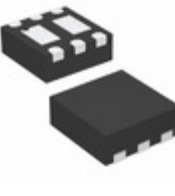
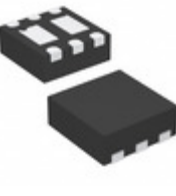

	<p>SIA511DJ-T1-GE3</p> <p>Manufacturer Part Number: SIA511DJ-T1-GE3</p> <p>Manufacturer/Brand: Electro-Films (EFI) / Vishay</p> <p>Part of Description: MOSFET N/P-CH 12V 4.5A SC70-6</p> <p>Datasheets:  SIA511DJ-T1-GE3.pdf</p> <p>RoHS Status:  Lead free / RoHS</p> <p>Stock Condition: Compliant New original, Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	SIA511DJ-T1-GE3
Manufacturer	Electro-Films (EFI) / Vishay
Description	MOSFET N/P-CH 12V 4.5A SC70-6
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	Require For Quote & Check Stock
Vgs(th) (Max) @ Id	1V @ 250µA
Supplier Device Package	PowerPAK® SC-70-6 Dual
Series	TrenchFET®
Rds On (Max) @ Id, Vgs	40 mOhm @ 4.2A, 4.5V
Power - Max	6.5W
Packaging	Cut Tape (CT)
Package / Case	PowerPAK® SC-70-6 Dual
Other Names	SIA511DJ-T1-GE3CT
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Capacitance (Ciss) (Max) @ Vds	400pF @ 6V
Gate Charge (Qg) (Max) @ Vgs	12nC @ 8V
FET Type	N and P-Channel
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	12V
Detailed Description	Mosfet Array N and P-Channel 12V 4.5A 6.5W Surface
Current - Continuous Drain (Id) @ 25°C	4.5A
Base Part Number	SIA511

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<p>In:</p>  <p>SIA483DJ-T1-GE3 Vishay Siliconix MOSFET P-CH 30V 12A SC70-6</p>	 <p>SIA477EDJT-T1-GE3 Vishay Siliconix MOSFET P-CH 12V 12A SC70-6</p>	 <p>SIA485DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CHANNEL 150V 1.6A</p>	 <p>SIA513DJ-T1-GE3 Vishay Siliconix MOSFET N/P-CH 20V 4.5A SC70-6</p>
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SIA511DJ-T1-GE3 Price	SIA511DJ-T1-GE3 Original	SIA511DJ-T1-GE3 Picture	SIA511DJ-T1-GE3 Stock	SIA511DJ-T1-GE3 Inventory
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